=> d his

US 2004154526

WO 2004072319

A1

A2

20040812

20040826

US 2004-772444

WO 2004-US3518

20040206

20040206

(FILE 'HOME' ENTERED AT 12:35:29 ON 19 JAN 2005)

```
FILE 'USPATFULL, USPAT2' ENTERED AT 12:35:40 ON 19 JAN 2005
          22597 S (FREE(W)STAND?)
L1
L2
           3456 S (PLURAL? OR MULTIP?) (8A) (FACET#)
L3
           5335 S (DIAMOND(4A)LAYER#)
L4
          11667 S (UNIFORM?) (6A) (DEPTH#)
L5
         231083 S (MOLD#)
           5669 S (DEPOSIT?) (8A) (BACK? (6A) LAYER#)
1.6
L7
          45014 S (REMOV?) (8A) (MOLD)
L8
         718998 S (CARBON)
Ь9
         236795 S (PLASMA)
L10
              1 S L1 AND L2 AND L3 AND L4 AND L5 AND L6 AND L7 AND L8 AND
L11
              1 S L1 AND L2 AND L3 AND L5 AND L6
     FILE 'HCAPLUS, INSPEC, JAPIO, USPATFULL, USPAT2' ENTERED AT 12:39:12 ON
     19 JAN 2005
              1 S L10
L12
          30449 S (FREE(W)STAND?)
L13
L14
           3847 S (PLURAL? OR MULTIP?) (8A) (FACET#)
          11576 S (DIAMOND (4A) LAYER#)
L15
          15660 S (UNIFORM?) (6A) (DEPTH#)
L16
L17 ,
         515213 S (MOLD#)
L18
           6722 S (DEPOSIT?) (8A) (BACK? (6A) LAYER#)
L19
          55525 S (REMOV?) (8A) (MOLD)
L20
        2121439 S (CARBON)
L21
        1359905 S (PLASMA)
L22
              1 S L12 AND L13 AND L14 AND L15 AND L16 AND L17 AND L18 AND L19 A
L23
              1 S L13 AND L14 AND L15 AND L16 AND L17 AND L18 AND L19 AND L20 A
L24
              2 S L13 AND L14 AND L15
=> d 124 1-2 abs,bib
     ANSWER 1 OF 2 HCAPLUS COPYRIGHT 2005 ACS on STN
L24
     The invention is directed in one aspect to methods of making free
     -standing, internally-supported, three-dimensional objects
     having an outer surface comprising a plurality of intersecting
     facets wherein a sub-set of the intersecting facets have a
     diamond layer of substantially uniform thickness. The
     diamond layer may be formed by chemical vapor deposition
     (CVD) over the surface of a substrate that was fabricated to form a mold
     defining the sub-set of intersecting facets. A backing layer may be
     formed over at least a portion of the exposed diamond
     layer to enhance the rigidity of the layer when the substrate is
     removed.
ΑN
     2004:654706 HCAPLUS
DN
     141:178252
ΤI
     Method of making free-standing, internally-supported,
     three-dimensional diamond structures
IN
     Mearini, Gerald T.; Dayton, James A.
PA
SO
     U.S. Pat. Appl. Publ., 5 pp.
     CODEN: USXXCO
DT
     Patent
LΑ
     English
FAN.CNT 1
     PATENT NO.
                          KIND
                                             APPLICATION NO.
                                                                     DATE
                          ----
```

```
AE, AE, AG, AL, AL, AM, AM, AM, AT, AT, AU, AZ, AZ, BA, BB, BG,
              BG, BR, BR, BW, BY, BY, BZ, BZ, CA, CH, CN, CN, CO, CO, CR, CR,
              CU, CU, CZ, CZ, DE, DE, DK, DK, DM, DZ, EC, EC, EE, EE, EG, ES,
              ES, FI, FI, GB, GD, GE, GE, GH, GM, HR, HR, HU, HU, ID, IL, IN,
              IS, JP, JP, KE, KE, KG, KG, KP, KP, KP, KR, KR, KZ, KZ, KZ, LC,
              LK, LR, LS, LS, LT, LU, LV, MA, MD, MD, MG, MK, MN, MW, MX, MX,
              MZ, MZ, NA, NÌ
         RW: BW, GH, GM, KE, LS, MW, MZ, SD, SL, SZ, TZ, UG, ZM, ZW, AT, BE,
              BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HU, IE, IT, LU,
              MC, NL, PT, RO, SE, SI, SK, TR, BF, BJ, CF, CG, CI, CM, GA, GN, GQ, GW, ML, MR, NE, SN, TD, TG, BF, BJ, CF, CG, CI, CM, GA, GN,
              GQ, GW, ML, MR, NE, SN, TD, TG
PRAI US 2003-445237P
                            Р
                                  20030206
                            P
                                   20030812
     US 2003-494089P
     US 2003-494095P
                            ₽
                                   20030812
L24
     ANSWER 2 OF 2 USPATFULL on STN .
AB
       The present invention is directed in one aspect to methods of making
       free-standing, internally-supported, three-dimensional
       objects having an outer surface comprising a plurality of
       intersecting facets wherein a sub-set of the intersecting
       facets have a diamond layer of substantially uniform
       thickness. The diamond layer may be formed by
       chemical vapor deposition (CVD) over the surface of a substrate that has
       been fabricated to form a mold defining the sub-set of intersecting
       facets. A backing layer may be formed over at least a portion of the
       exposed diamond layer to enhance the rigidity of the
       layer when the substrate is removed.
CAS INDEXING IS AVAILABLE FOR THIS PATEN
       2004:200643 USPATFULL
AN
       Free-standing diamond structures and methods
Mearini, Gerald T., Shaker Heights, OH UNIT
TΤ
IN
                                                  UNITED STATES
                                the world and, OH WUNITED STATES
       Dayton, James A., JR.,
                                  20040812
PΙ
       US 2004154526
                            A1
                                  20040206
      US 2004-772444
                            A1
ΑI
                            (20030206) (60)
(20030813) (60)
PRAI
       US 2003-445237P
       US 2003-494089P
                               0030812
       US 2003-494095P
DT
       Utility
       APPLICATION
FS
       D. JOSEPH ENGLISH, Duane Morris LLP, Suite 770, 1667 K Street, N.W.,
LREP
       Washington, DC, 20006
CLMN
       Number of Claims: 34
ECL
       Exemplary Claim: 1
DRWN
        1 Drawing Page(s)
LN.CNT 284
```

CAS INDEXING IS AVAILABLE FOR THIS PATENT.

Search History

=> d his

=>

(FILE 'HOME' ENTERED AT 12:35:29 ON 19 JAN 2005)

```
FILE 'USPATFULL, USPAT2' ENTERED AT 12:35:40 ON 19 JAN 2005
            22597 S (FREE(W) STAND?)
L1
L2
             3456 S (PLURAL? OR MULTIP?) (8A) (FACET#)
L3
             5335 S (DIAMOND (4A) LAYER#)
            11667 S (UNIFORM?) (6A) (DEPTH#)
L4
           231083 S (MOLD#)
L5
             5669 S (DEPOSIT?) (8A) (BACK? (6A) LAYER#)
L6
L7
            45014 S (REMOV?) (8A) (MOLD)
L8
           718998 S (CARBON)
L9
           236795 S (PLASMA)
=> s 11 and 12 and 13 and 14 and 15 and 16 and 17 and 18 and 19
L10
                1 L1 AND L2 AND L3 AND L4 AND L5 AND L6 AND L7 AND L8 AND
=> d 110 abs,bib
      ANSWER 1 OF 1 USPATFULL on STN
AB
        The present invention is directed in one aspect to methods of making
         free-standing, internally-supported, three-dimensional
        objects having an outer surface comprising a plurality of
        intersecting facets wherein a sub-set of the intersecting facets have a diamond layer of substantial puniform
        thickness. The diamond layer may be formed by chemical vapor deposition (CVD) over the surface of a substrate that has
        been fabricated to form a mold designing the sub-set of intersecting facets. A backing rever may be formed over at least a portion of the expessed diamond layer to enhance the
        rigidity of the layer when the substrate is removed
CAS INDEXING IS AVAILABLE FOR TRUS PATENT.
        2004:200643 USPATHULA
AN
        Free-standing diamond structures and methods
ΤI
        Mearini, Gerald T., Shakex Heights, OH, UNITED STATES
IN
        Dayton, James A., JR., Cleveland, OH, UNITED STATES US 2004154526 A1 20040812
PI
                                     20040206 (10)
        US 2004-772444
ΑI
                               A1
PRAI
        US 2003-445237P
                                20030206 (60)
        US 2003-494089P
                                20030812 (60)
        US 2003-494095P
                                20030812 (60)
DT
        Utility
FS
        APPLICATION
        D. JOSEPH ENGLISH, Duane Morris LLP, Suite 770, 1667 K Street, N.W.,
LREP
        Washington, DC, 20006
CLMN
        Number of Claims: 34
ECL
        Exemplary Claim: 1
DRWN
         1 Drawing Page(s)
LN.CNT 284
CAS INDEXING IS AVAILABLE FOR THIS PATENT.
```